

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

APPLICATIONS / BENEFITS Suppresses transients up to 1500 watts @ 10/1000 μs (see Figure 1) Clamps transient in less than 100 pico seconds Protection from switching transients and induced RF Protection from ESD and EFT per IEC 61000-4-2 and IEC 61000-4-4 Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance: Class 1: 1N5555 to 1N5558 Class 2 & 3: 1N5555 to 1N5557 Class 4: 1N5555 to 1N5556 Secondary lightning protection per IEC61000-4-5 with 12 Ohms source impedance: Class 1: 1N5555 to 1N5557 Class 1: 1N5555 to 1N5557 Class 2: 1N5555 to 1N5557

Inherently radiation hard as described in Microsemi MicroNote 050

MAXIMUM RATINGS

- > 1500 Watts for 10/1000 μ s with repetition rate of 0.01% or less* at lead temperature (T_L) 25°C (see Figs 1, 2, & 4)
- > Operating & Storage Temperatures: -65° to $+175^{\circ}$ C
- THERMAL RESISTANCE: 50°C/W junction to lead at 0.375 inches (10 mm) from body or 110°C/W junction to ambient when mounted on FR4 PC board with 4 mm² copper pads (1oz) and track width 1 mm, length 25 mm
- > DC Power Dissipation*: 1 Watt at $T_L = +25^{\circ}C 3/8^{\circ}$ (10 mm) from body (see derating in Fig 3)
- > Forward surge current: 200 Amps for 8.3ms half-sine wave at $T_A = +25^{\circ}C$
- Solder Temperatures: 260 ° C for 10 s (maximum)

MECHANICAL AND PACKAGING

- > CASE: DO-13 (DO-202AA), welded, hermetically sealed metal and glass
- > FINISH: All external metal surfaces are Tin-Lead plated and solderable per MIL-STD-750 method 2026
- > POLARITY: Cathode connected to case and polarity indicated by diode symbol
- > MARKING: Part number and polarity diode symbol
- ➢ WEIGHT: 1.4 grams. (Approx)
- > TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- See package dimension on last page
- * TVS devices are not typically used for dc power dissipation and are instead operated at or less than their rated standoff voltage

 (V_{WM}) except for transients that briefly drive the device into avalanche breakdown (V_{BR} to V_C region).



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JEDEC Type Number Notes 1&2)	Minimum Breakdown Voltage V _(BR) @ I _(BR)	Test Current I _(BR)	Rated Standoff Voltage V _{WM}	Maximum (RMS) Reverse Voltage V _{WM(RMS)}	Maximum Standby Current I _D @ V _{WM}	Maximum Peak Reverse Voltage V _C @ I _{PP}	Maximum Peak Pulse Current I _{PP}	Maximum Temperature Coefficient of V _(BR) α _{V(BR)} @ 1.0 mA
	V	mA	V	V	μA	V	Α	%/°C
1N5555 1N5556 1N5557	33.0 43.7 54.0	1.0 1.0 1.0	30.5 40.3 49.0	21.5 28.5 34.5	5 5 5	47.5 63.5 78.5	32 24 19	+.093 +.094 +.096

NOTE 1: A TVS is normally selected according to the rated "Standoff Voltage" V_{WM} that should be equal to or greater than the dc or continuous peak operating voltage level.

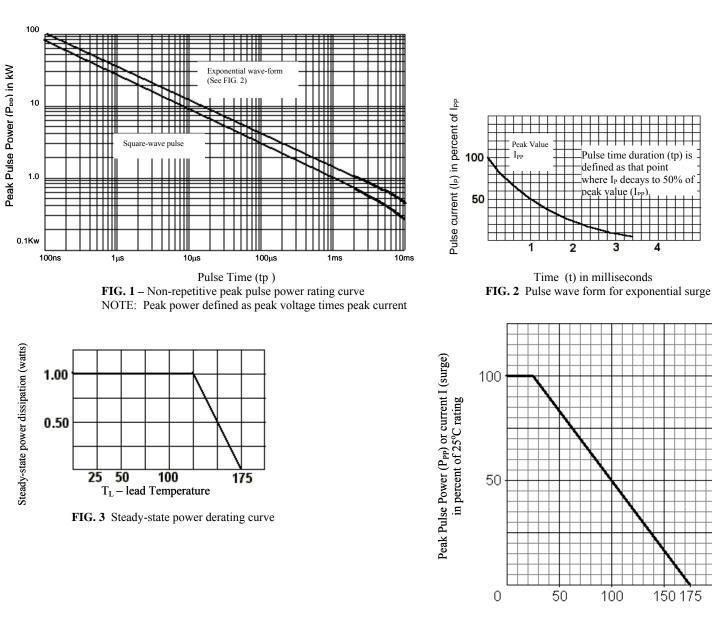
	SYMBOLS & DEFINITIONS						
Symbol	Definition						
$V_{\rm WM}$	Standoff Voltage: Applied Reverse Voltage to assure a nonconductive condition. (See Note 1 above.)						
V _(BR)	Breakdown Voltage: This is the Breakdown Voltage the device will exhibit at 25°C						
V _C	Maximum Clamping Voltage: The maximum peak voltage appearing across the TVS when subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltage is the combination of voltage rise due to both the series resistance and thermal rise and positive temperature coefficient ($\alpha_{V(BR)}$)						
I_{PP}	Peak Pulse Current: The peak current during the impulse (See Figure 2)						
$\mathbf{P}_{\mathbf{PP}}$	Peak Pulse Power: The pulse power as determined by the product of V_C and I_{PP}						
I _D	Standby Current: The current at the standoff voltage (V_{WM})						
I _(BR)	Breakdown Current: The current used for measuring Breakdown Voltage $(V_{(BR)})$						

NOTE 2: Also available in military qualified types with a JAN, JANTX, or JANTXV prefix.



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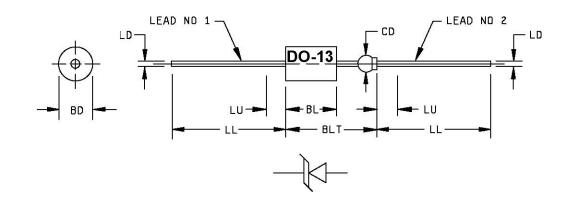


T_A Ambient Temperature ^oC **FIG. 4** Derating Curve



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PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. The major diameter is essentially constant along its length.
- 4. Within this zone, diameter may vary to allow for lead finishes and irregularities.
- 5. Dimension to allow for pinch or seal deformation anywhere along tubulation.
- 6. Lead 1 (cathode) shall be electrically connected to the case.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

Symbol	Inc	hes	Millir	Notes	
	Min	Max	Min	Max	
BD	.215	.235	5.46	5.97	
BL	.293	.357	7.44	9.07	3
BLT		.570		14.48	
CD	.045	.100	1.14	2.54	5
LD	.025	.035	0.64	0.89	
LL	1.000	1.625	25.40	41.28	4
LU		.188		4.78	4

FIGURE 1. Physical dimensions (DO-13).